

CSD25211W1015, P-Channel NexFET™ Power MOSFET

 Check for Samples: [CSD25211W1015](#)

FEATURES

- Ultra-Low On Resistance
- Ultra-Low Q_g and Q_{gd}
- Small Footprint 1.0 mm × 1.5 mm
- Low Profile 0.62 mm Height
- Pb Free
- Gate-Source Voltage Clamp
- Gate ESD Protection – 3 kV
- RoHS Compliant
- Halogen Free

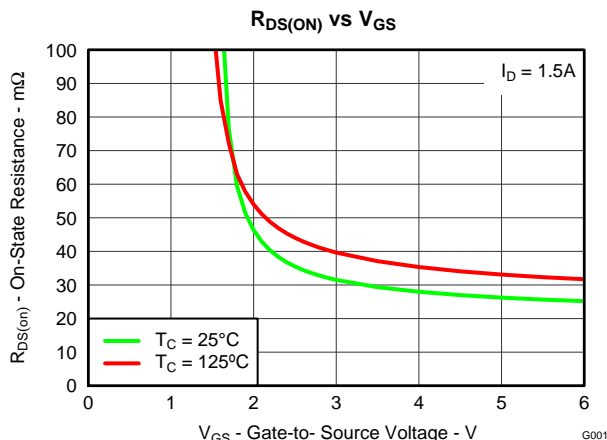
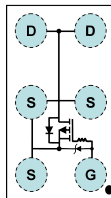
APPLICATIONS

- Battery Management
- Load Switch
- Battery Protection

DESCRIPTION

The device is designed to deliver the lowest on resistance and gate charge in the smallest outline possible with excellent thermal characteristics in an ultra-low profile.

Top View



PRODUCT SUMMARY

$T_A = 25^\circ\text{C}$ unless otherwise stated		TYPICAL VALUE		UNIT
V_{DS}	Drain-to-Source Voltage	-20		V
Q_g	Gate Charge Total (-4.5V)	3.4		nC
Q_{gd}	Gate Charge Gate to Drain	0.2		nC
$R_{DS(on)}$	Drain-to-Source On Resistance	$V_{GS} = -2.5\text{ V}$	36	m Ω
		$V_{GS} = -4.5\text{ V}$	27	m Ω
$V_{GS(th)}$	Voltage Threshold	-0.8		V

ORDERING INFORMATION

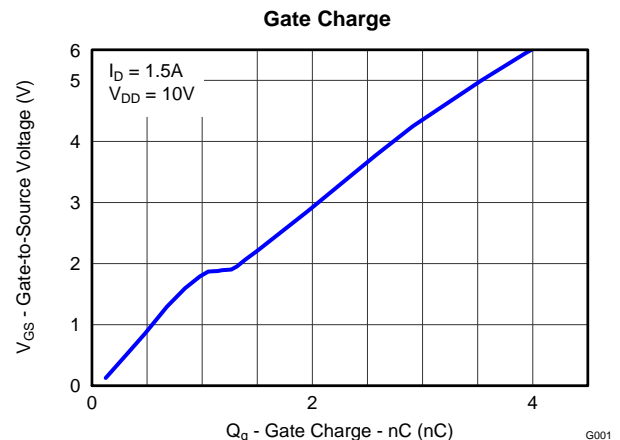
Device	Package	Media	Qty	Ship
CSD25211W1015	1 × 1.5 Wafer Level Package	7-inch reel	3000	Tape and Reel

ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$ unless otherwise stated		VALUE	UNIT
V_{DS}	Drain-to-Source Voltage	-20	V
V_{GS}	Gate-to-Source Voltage	-6	V
I_D	Continuous Drain Current, $T_A = 25^\circ\text{C}^{(1)}$	-3.2	A
I_{DM}	Pulsed Drain Current, $T_A = 25^\circ\text{C}^{(2)}$	-9.5	A
I_G	Continuous Drain Current, $T_A = 25^\circ\text{C}$	-0.5	A
	Pulsed Drain Current	-7	A
P_D	Power Dissipation ⁽¹⁾	1	W
T_{STG}	Storage Temperature Range	-55 to 150	$^\circ\text{C}$
T_J	Operating Junction Temperature Range		

(1) Typical $R_{\theta JA} = 119^\circ\text{C/W}$ on 1 inch² of 2 oz. Cu on 0.06-inch thick FR4 PCB.

(2) Pulse width $\leq 10\ \mu\text{s}$, duty cycle $\leq 2\%$



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ELECTRICAL CHARACTERISTICS

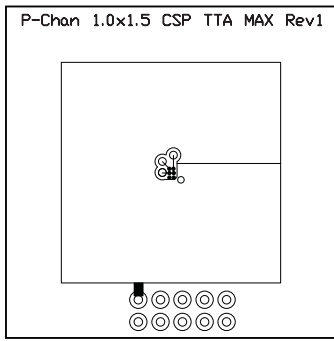
(T_A = 25°C unless otherwise stated)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Static Characteristics						
B _V DSS	Drain-to-Source Voltage	V _{GS} = 0 V, I _D = -250 μA	-20			V
B _V GSS	Gate-to-Source Voltage	V _{DS} = 0 V, I _G = -250 μA	-6.1		-7.2	V
I _{DSS}	Drain-to-Source Leakage Current	V _{GS} = 0 V, V _{DS} = -16 V			-1	μA
I _{GSS}	Gate-to-Source Leakage Current	V _{DS} = 0 V, V _{GS} = -6 V			-100	nA
V _{GS(th)}	Gate-to-Source Threshold Voltage	V _{DS} = V _{GS} , I _D = -250 μA	-0.5	-0.8	-1.1	V
R _{DS(on)}	Drain-to-Source On Resistance	V _{GS} = -2.5 V, I _D = -1.5 A		36	44	mΩ
		V _{GS} = -4.5 V, I _D = -1.5 A		27	33	mΩ
g _{fs}	Transconductance	V _{DS} = -10 V, I _D = -1.5 A		12		S
Dynamic Characteristics						
C _{ISS}	Input Capacitance	V _{GS} = 0V, V _{DS} = -10V, f = 1MHz		475	570	pF
C _{OSS}	Output Capacitance			234	281	pF
C _{RSS}	Reverse Transfer Capacitance			10.5	13.1	pF
Q _g	Gate Charge Total (-4.5 V)	V _{DS} = -10V, I _D = -1.5A		3.4	4.1	nC
Q _{gd}	Gate Charge Gate to Drain			0.2		nC
Q _{gs}	Gate Charge Gate to Source			1.1		nC
Q _{g(th)}	Gate Charge at V _{th}			0.6		nC
Q _{OSS}	Output Charge	V _{DS} = -10V, V _{GS} = 0V		3.8		nC
t _{d(on)}	Turn On Delay Time	V _{DS} = -10 V, V _{GS} = -4.5 V, I _D = -1.5 A R _G = 4 Ω		13.6		ns
t _r	Rise Time			8.8		ns
t _{d(off)}	Turn Off Delay Time			36.9		ns
t _f	Fall Time			14.2		ns
Diode Characteristics						
V _{SD}	Diode Forward Voltage	I _S = -1.5 A, V _{GS} = 0 V		-0.8	-1	V
Q _{rr}	Reverse Recovery Charge	V _{dd} = -10 V, I _F = -1.5 A, di/dt = 200 A/μs		6.9		nC
t _{rr}	Reverse Recovery Time			11.6		ns

THERMAL CHARACTERISTICS

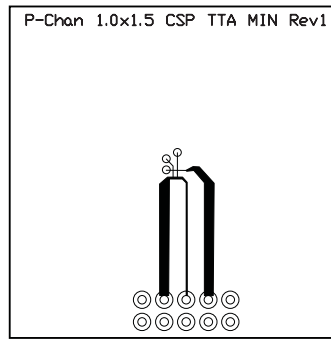
(T_A = 25°C unless otherwise stated)

PARAMETER		MIN	TYP	MAX	UNIT
R _{θJA}	Thermal Resistance Junction to Ambient (Minimum Cu area)			230	°C/W
	Thermal Resistance Junction to Ambient (1 in ² Cu area)			149	°C/W



M0155-01

Max $R_{\theta JA} = 149^{\circ}\text{C/W}$
when mounted on 1
 inch^2 of 2 oz. Cu.



M0156-01

Max $R_{\theta JA} = 230^{\circ}\text{C/W}$
when mounted on
minimum pad area of
 2 oz. Cu.

TYPICAL MOSFET CHARACTERISTICS

($T_A = 25^{\circ}\text{C}$ unless otherwise stated)

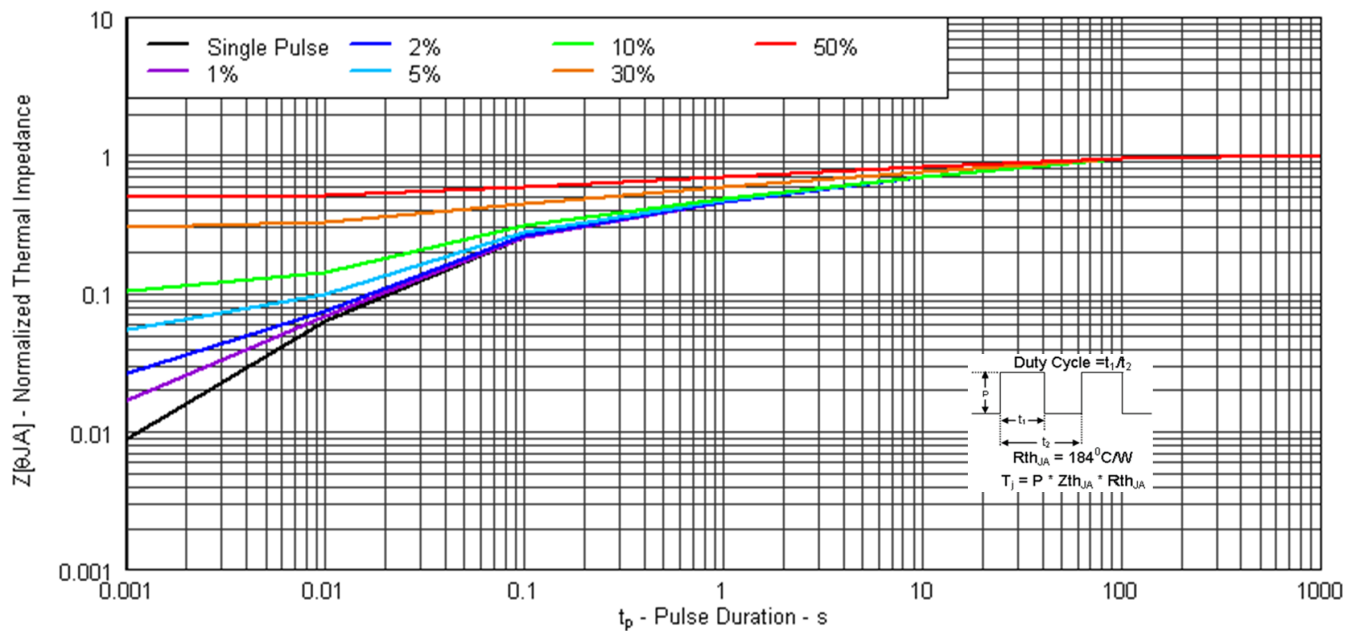


Figure 1. Transient Thermal Impedance

TYPICAL MOSFET CHARACTERISTICS (continued)

($T_A = 25^\circ\text{C}$ unless otherwise stated)

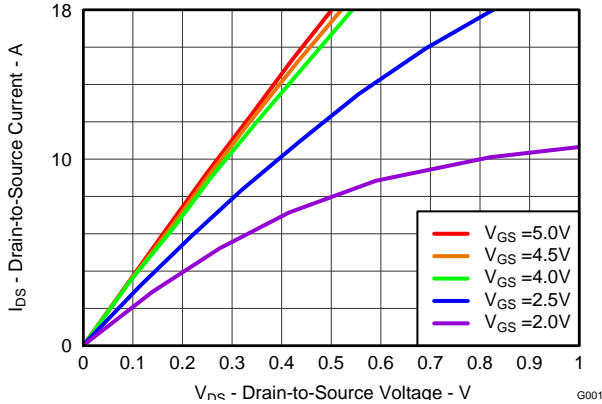


Figure 2. Saturation Characteristics

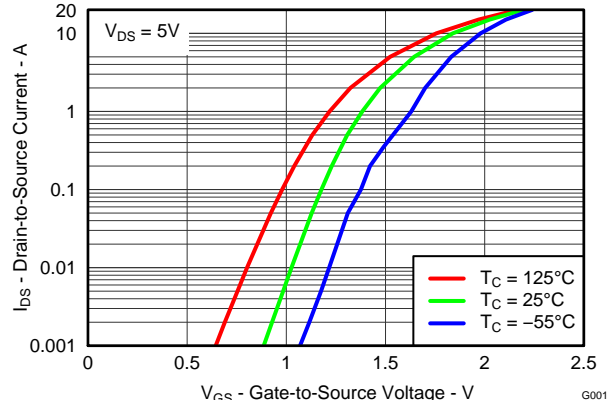


Figure 3. Transfer Characteristics

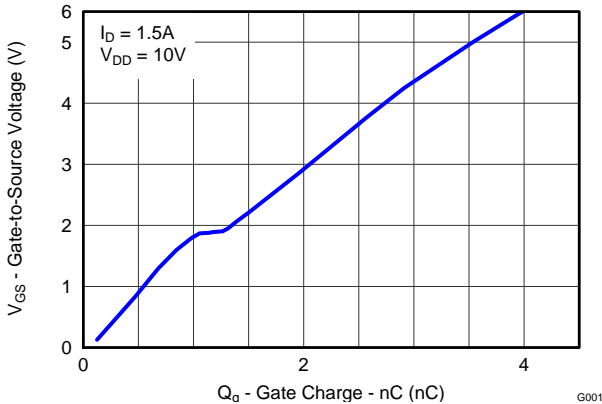


Figure 4. Gate Charge

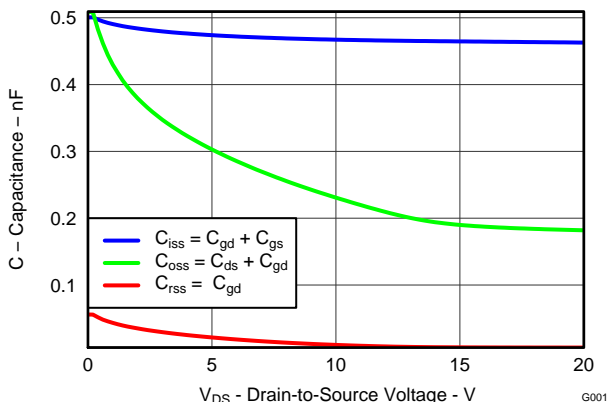


Figure 5. Capacitance

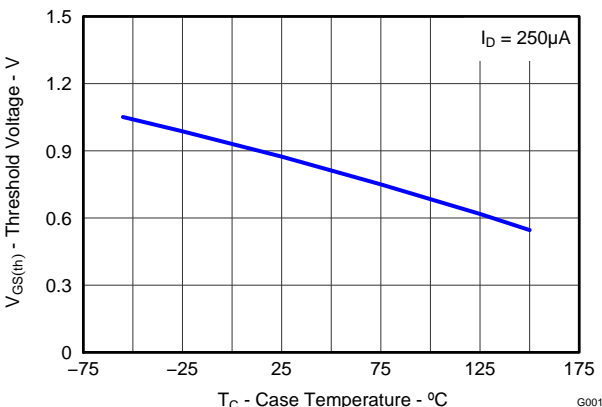


Figure 6. Threshold Voltage vs Temperature

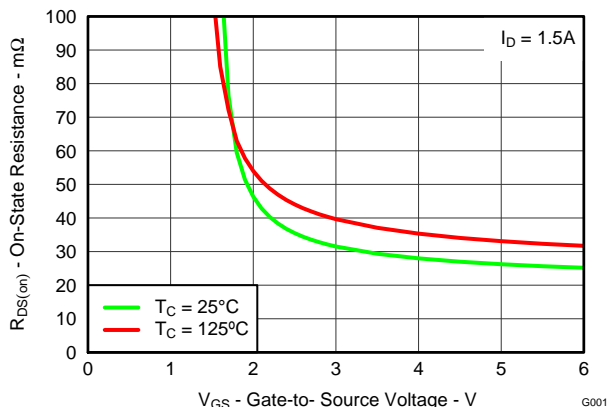


Figure 7. On Resistance vs Gate Voltage

TYPICAL MOSFET CHARACTERISTICS (continued)

($T_A = 25^\circ\text{C}$ unless otherwise stated)

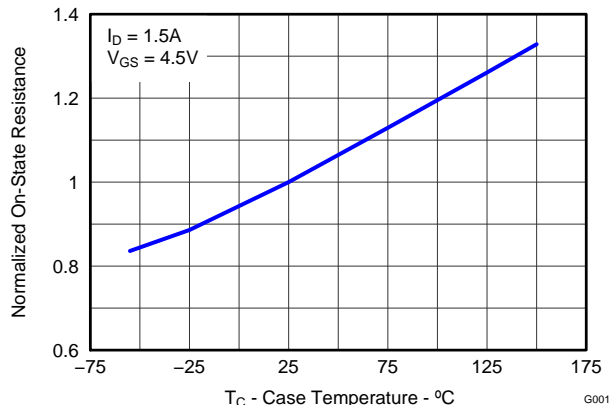


Figure 8. Normalized On Resistance vs Temperature

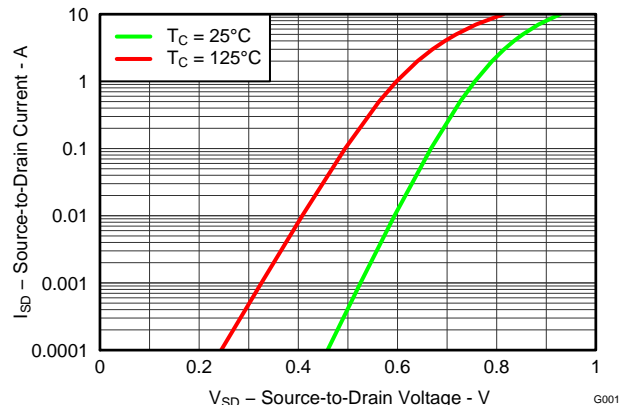


Figure 9. Typical Diode Forward Voltage

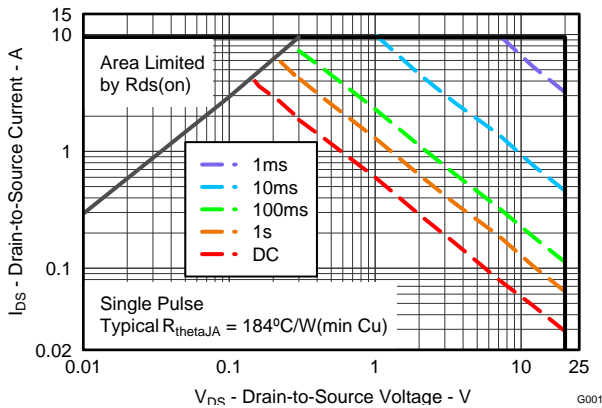


Figure 10. Maximum Safe Operating Area

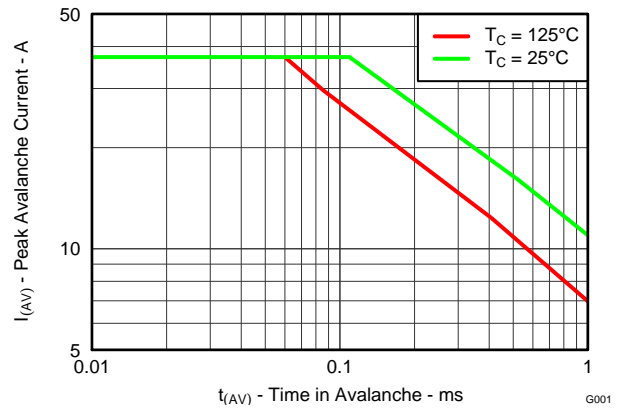


Figure 11. Single Pulse Unclamped Inductive Switching

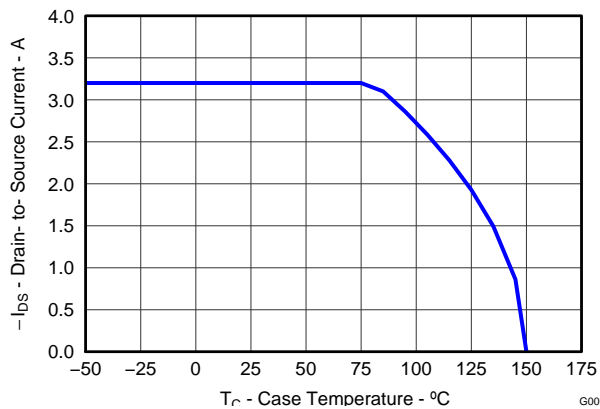
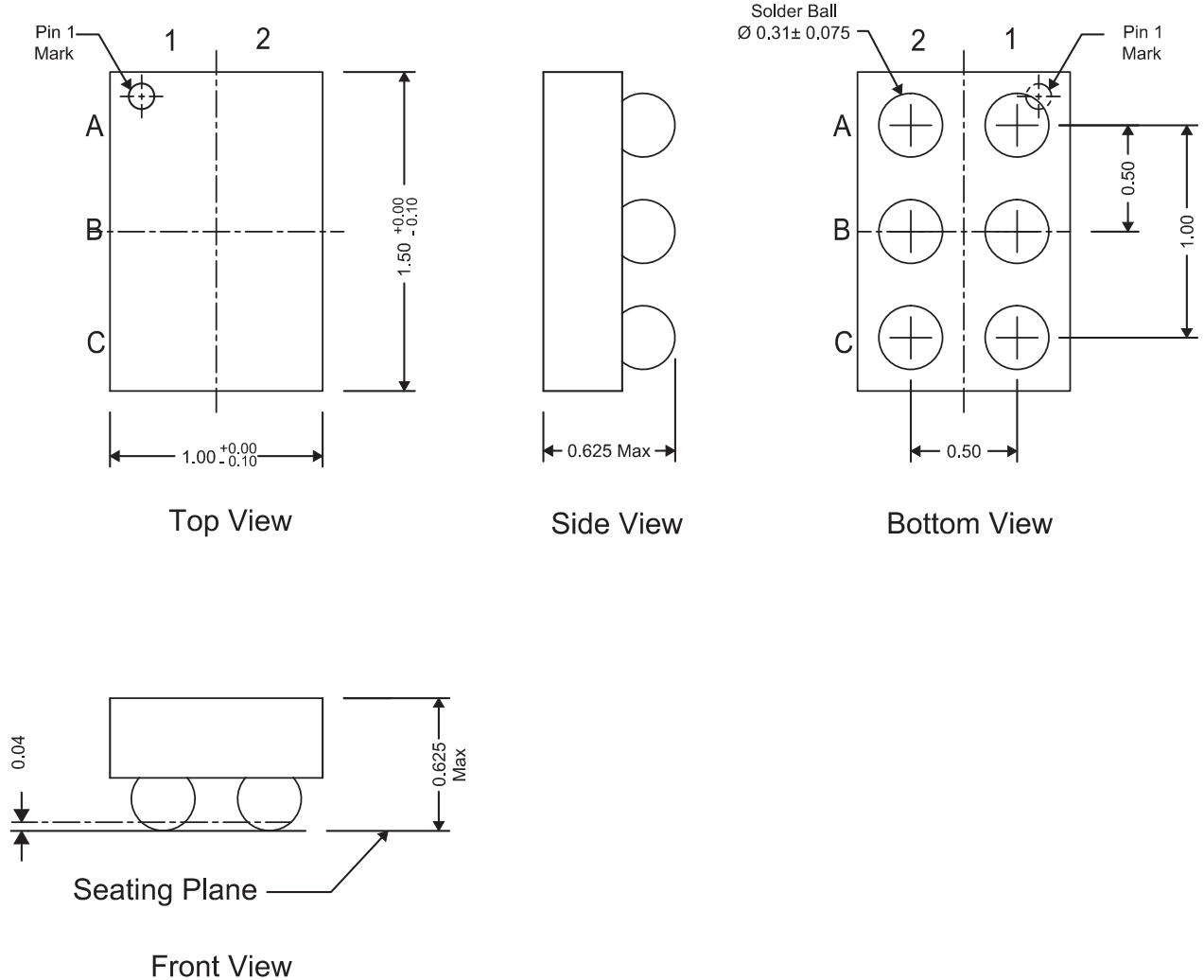


Figure 12. Maximum Drain Current vs Temperature

MECHANICAL DATA

CSD25211W1015 Package Dimensions

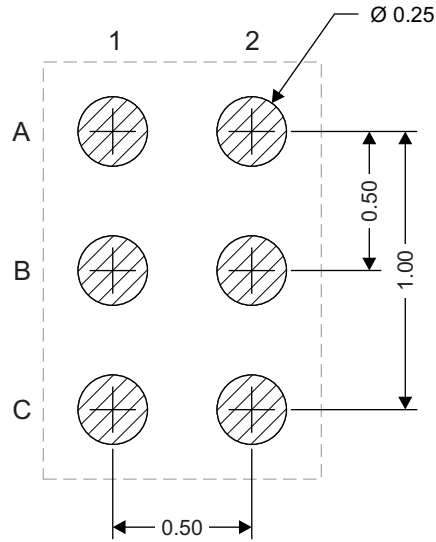


NOTE: All dimensions are in mm (unless otherwise specified)

Pinout

POSITION	DESIGNATION
C1, C2	Drain
A1	Gate
A2, B1, B2	Source

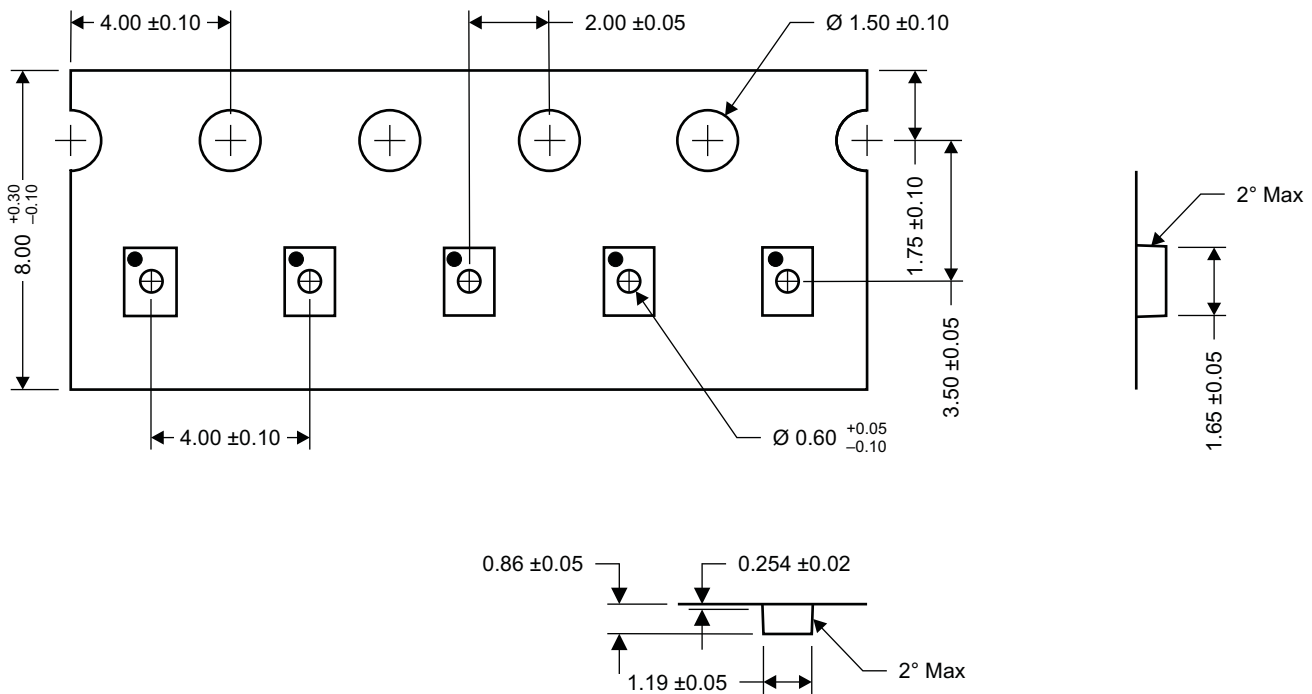
Land Pattern Recommendation



M0158-01

NOTE: All dimensions are in mm (unless otherwise specified)

Tape and Reel Information



M0159-01

NOTE: All dimensions are in mm (unless otherwise specified)

REVISION HISTORY

Changes from Original (February 2012) to Revision A	Page
• Included part number	1
• Added more precision	6

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
CSD25211W1015	ACTIVE	DSBGA	YZC	6	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-55 to 150	25211	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSELETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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